

1. General description

Planar passivated very sensitive gate four quadrant triac in a SOT223 (SC-73) surface-mountable plastic package intended for applications requiring direct interfacing to logic level ICs and low power gate drivers.

2. Features and benefits

- Direct interfacing to logic level ICs
- · Direct interfacing to low power gate drive circuits
- High blocking voltage capabiliy
- · Planar passivated for voltage ruggedness and reliability
- Surface-mountable package
- Triggering in all four quadrants
- Very sensitive gate in four quadrants

3. Applications

- General purpose low power motor control
- Home appliances
- Industrial process control
- Low power AC Fan controllers

4. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--|---|-----|-----|-----|------|
| V _{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{sp} ≤ 105 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 1 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | - | - | 8 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t _p = 16.7 ms | - | - | 8.5 | A |
| Tj | junction temperature | | - | - | 125 | °C |
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 V; I_T = 0.1 A; T2+G+;$ T _j = 25 °C; <u>Fig. 9</u> | - | - | 3 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _i = 25 °C; <u>Fig. 9</u> | - | - | 3 | mA |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---|-----|-----|-----|------|
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 9</u> | - | - | 3 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 9</u> | - | - | 5 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u> | - | - | 7 | mA |
| V _T | on-state voltage | I _T = 1.4 A; T _j = 25 °C; <u>Fig. 11</u> | - | 1.3 | 1.6 | V |
| Dynamic chara | acteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 110 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13 | 10 | - | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | V_D = 400 V; T _j = 110 °C; dI _{com} / dt = 0.44 A/ms; gate open circuit | 0.5 | - | - | V/µs |

5. Pinning information

| Table 2. Pinning information | | | | | | | |
|------------------------------|--------|-----------------|----------------------------|----------------|--|--|--|
| Pin | Symbol | Description | Simplified outline | Graphic symbol | | | |
| 1 | T1 | main terminal 1 | 4 | T2-71 | | | |
| 2 | T2 | main terminal 2 | | G sym051 | | | |
| 3 | G | gate | | Symoor | | | |
| 4 | T2 | main terminal 2 | ∐1 ∐2 ∐3 SC-73 (SOT223) | | | | |

6. Ordering information

Table 3. Ordering information Type number Package Name Description Version Z0103MN SC-73 plastic surface-mounted package with increased heatsink; 4 leads SOT223

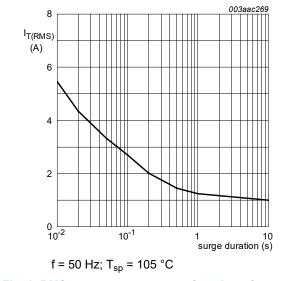
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7. Limiting values

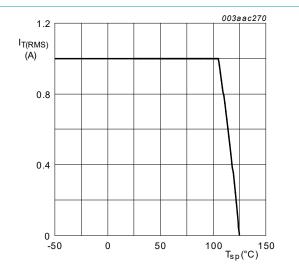
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--|---|-----|------|------|
| V _{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{sp} ≤ 105 °C; <u>Fig. 1; Fig. 2;</u> <u>Fig. 3</u> | - | 1 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5 | - | 8 | A |
| | | full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms | - | 8.5 | А |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | 0.32 | A²s |
| dl _T /dt | rate of rise of on-state current | I _G = 20 mA; T2+ G+ | - | 50 | A/µs |
| | | I _G = 20 mA; T2+ G- | - | 50 | A/µs |
| | | I _G = 20 mA; T2- G- | - | 50 | A/µs |
| | | I _G = 20 mA; T2- G+ | - | 20 | A/µs |
| I _{GM} | peak gate current | | - | 1 | А |
| P _{GM} | peak gate power | | - | 2 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.1 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

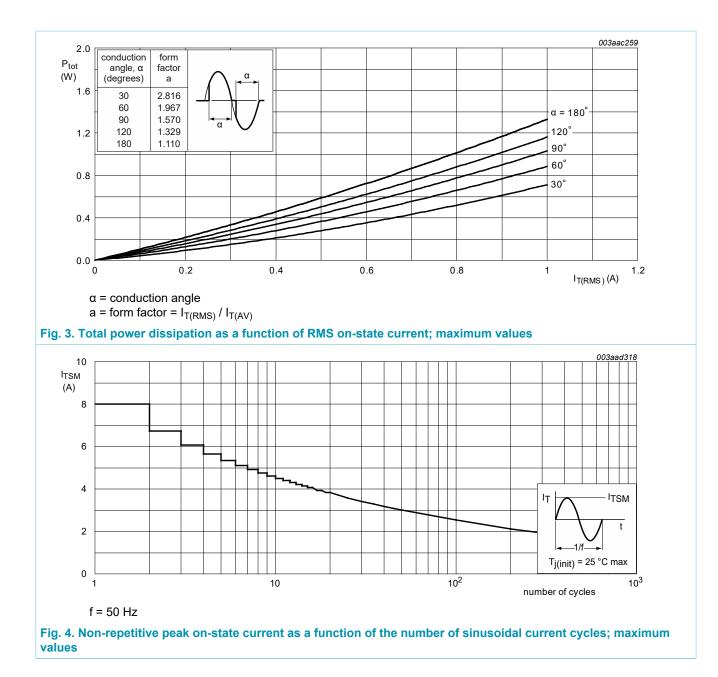






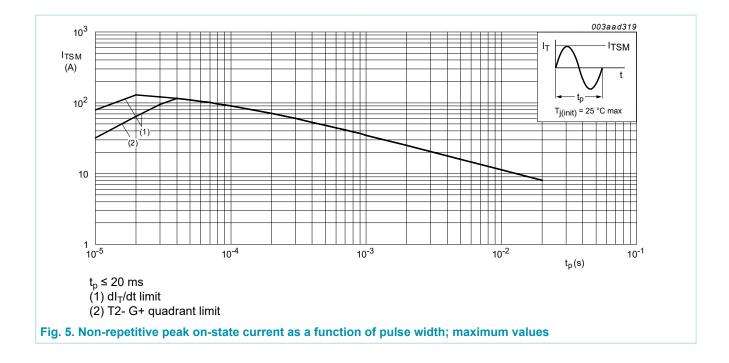


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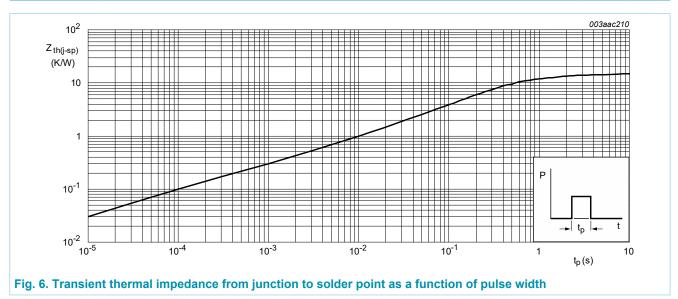
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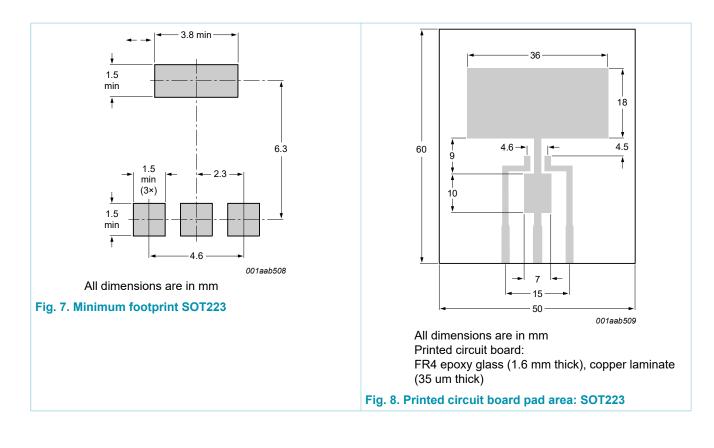
8. Thermal characteristics

| Table 5. The | rmal characteristics | | | | | |
|-----------------------|--|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-sp)} | thermal resistance from junction to solder point | full cycle; <u>Fig. 6</u> | - | - | 15 | K/W |
| R _{th(j-a)} | thermal resistance from junction to | full cycle; printed circuit board mounted; minimum footprint; Fig. 7 | - | 156 | - | K/W |
| | ambient free air | full cycle; printed circuit board mounted; pad area; Fig. 8 | - | 70 | - | K/W |



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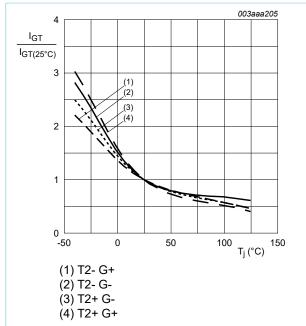
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9. Characteristics

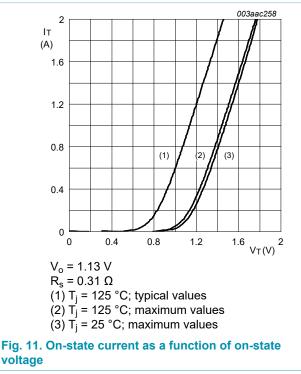
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---|-----|-----|-----|------|
| Static chara | cteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 9</u> | - | - | 3 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 9 | - | - | 3 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 9</u> | - | - | 3 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 9</u> | - | - | 5 | mA |
| L | latching current | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 10 | - | - | 7 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 10 | - | - | 15 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 10 | - | - | 7 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 10 | - | - | 7 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u> | - | - | 7 | mA |
| V _T | on-state voltage | I _T = 1.4 A; T _j = 25 °C; <u>Fig. 11</u> | - | 1.3 | 1.6 | V |
| V _{GT} | gate trigger voltage | V _D = 600 V; I _T = 0.1 A; T _j = 125 °C | 0.2 | - | - | V |
| | | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 12 | - | - | 1 | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | - | 0.5 | mA |
| Dynamic ch | aracteristics | · · · | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 110 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13 | 10 | - | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | $V_D = 400 \text{ V}; \text{ T}_j = 110 \text{ °C}; \text{ dI}_{com}/$ dt = 0.44 A/ms; gate open circuit | 0.5 | - | - | V/µs |

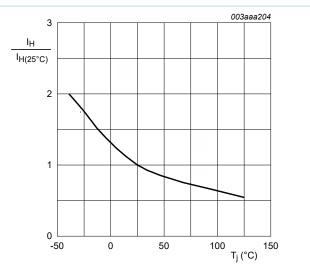
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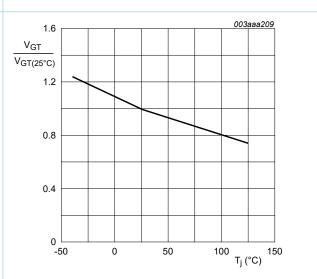








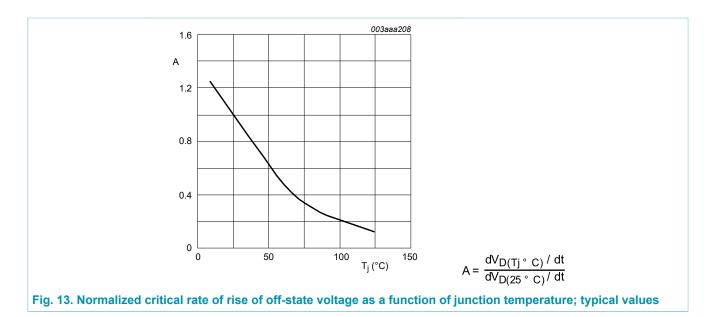






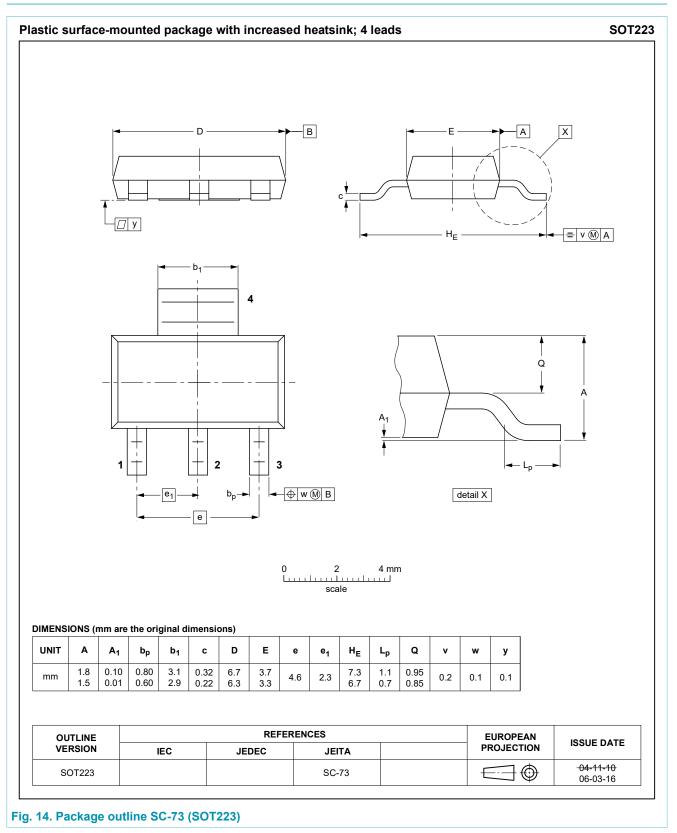
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10. Package outline



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11. Legal information

Data sheet status

| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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- [2] The term 'short data sheet' is explained in section "Definitions".
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